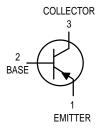
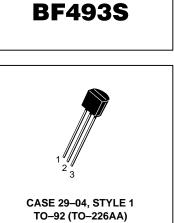
High Voltage Transistor PNP Silicon





MAXIMUM RATINGS

| Symbol | Value | Unit | |
|-----------------------------------|--|---|--|
| VCEO | -350 | Vdc | |
| V _{CBO} | -350 | Vdc | |
| V _{EBO} | -6.0 | Vdc | |
| ΙC | -500 | mAdc | |
| PD | 625 5.0 | Watts mW/°C | |
| PD | 1.5 12 | | |
| T _J , T _{stg} | -55 to +150 | °C | |
| | VCEO VCBO VEBO IC PD PD | VCEO -350 VCBO -350 VEBO -6.0 IC -500 PD 625 5.0 5.0 PD 1.5 12 12 | |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit | |
|---|-------------------|------|------|--|
| Thermal Resistance, Junction to Ambient | $R_{	hetaJA}$ | 200 | °C/W | |
| Thermal Resistance, Junction to Case | R _θ JC | 83.3 | °C/W | |

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
|---|-----------------------|------|----------------|------|
| OFF CHARACTERISTICS | | | | |
| Collector-Emitter Breakdown Voltage (1) ($I_C = -1.0 \text{ mAdc}, I_B = 0$) | V _(BR) CEO | -350 | — | Vdc |
| Collector-Base Breakdown Voltage $(I_{C} = -100 \ \mu Adc, I_{E} = 0)$ | V _(BR) CBO | -350 | _ | Vdc |
| Emitter–Base Breakdown Voltage (I _E = −100 μAdc, I _C = 0) | V(BR)EBO | -6.0 | — | Vdc |
| Collector Cutoff Current (V _{CE} = -250 Vdc) | ICES | — | -10 | nAdc |
| Emitter Cutoff Current ($V_{EB} = -6.0 \text{ Vdc}, I_{C} = 0$) | IEBO | _ | 0.1 | μAdc |
| Collector Cutoff Current ($V_{CB} = -250 \text{ Vdc}, I_E = 0, T_A = 25^{\circ}\text{C}$) ($V_{CB} = -250 \text{ Vdc}, I_E = 0, T_A = 100^{\circ}\text{C}$) | ICBO | _ | -0.005 -1.0 | μAdc |

1. Pulse Test: Pulse Width \leq 300 µs; Duty Cycle \leq 2.0%.

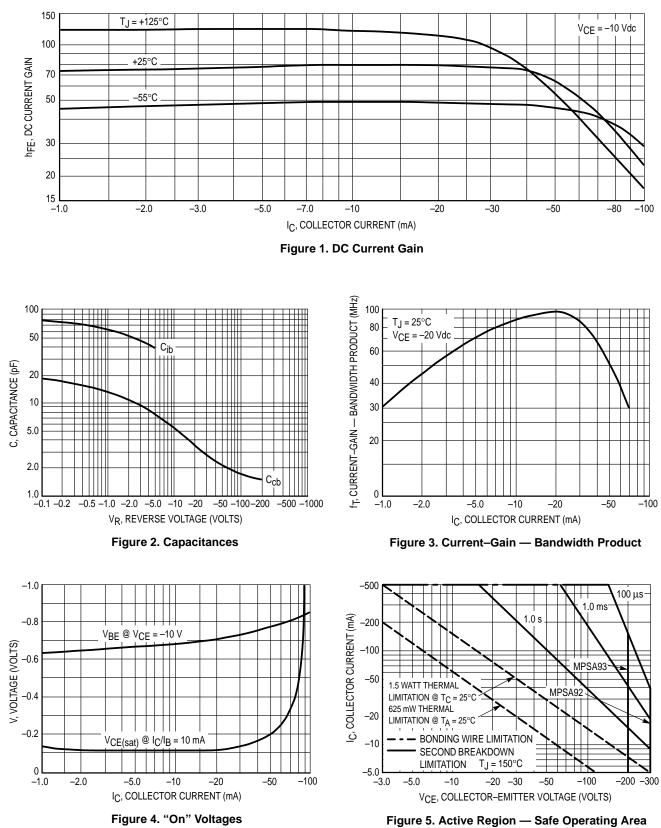


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ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

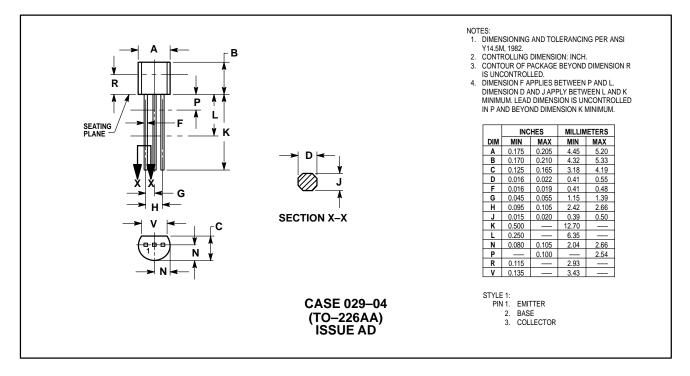
| Characteristic | Symbol | Min | Max | Unit |
|--|----------------------|----------|------|------|
| ON CHARACTERISTICS | | | - | |
| DC Current Gain ($I_C = -1.0 \text{ mAdc}$, $V_{CE} = -10 \text{ Vdc}$) ($I_C = -10 \text{ mAdc}$, $V_{CE} = -10 \text{ Vdc}$) | hFE | 25 40 | _ | _ |
| Collector-Emitter Saturation Voltage ($I_C = -20 \text{ mAdc}, I_B = -2.0 \text{ mAdc}$) | VCE(sat) | _ | -2.0 | Vdc |
| Base – Emitter On Voltage ($I_C = -20 \text{ mA}, I_B = -2.0 \text{ mA}$) | V _{BE(sat)} | _ | -2.0 | Vdc |
| DYNAMIC CHARACTERISTICS | | | | |
| Current-Gain — Bandwidth Product (I _C = -10 mAdc, V _{CE} = -20 Vdc, f = 20 MHz) | fT | 50 | _ | MHz |
| Common–Emitter Feedback Capacitance (V _{CB} = -100 Vdc, I _E = 0, f = 1.0 MHz) | C _{re} | — | 1.6 | pF |

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PACKAGE DIMENSIONS



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